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[54] SCINTILLATION MATERIAL ON THE BASE OF CESIUM IODIDE AND METHOD FOR ITS PREPARATION

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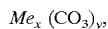
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[57] ABSTRACT

A cesium iodide based scintillation material is obtained exhibiting a low afterglow and high radiation hardness; its preparation method is developed, too.

The cesium iodide based scintillation material doped by thallium iodide contains an additional admixture of compound having the general formula



where Me is a cationic admixture,

$$1 \leq X \leq 2,$$

$$1 \leq Y \leq 5,$$

This material has in its absorption spectrum a stretching vibration band of CO_3^{2-} -ion about $7 \mu m$ and a bending vibration band about $11.4 \mu m$, the absorption coefficient of the latter being from $1.4 \cdot 10^{-3}$ to $2 \cdot 10^{-2} cm^{-1}$.

Preparation method of this scintillation material comprises the raw material cesium iodide melting, adding of the activating thallium iodide dope, introduction of cesium carbonate ($3 \cdot 10^{-4}$ to $5 \cdot 10^{-3}$ % by mass) and a sodium salt ($3 \cdot 10^{-4}$ to $7.5 \cdot 10^{-3}$ % of Na by mass) into said raw material and/or the melt and a subsequent crystallization.

7 Claims, No Drawings